

New crystal structures of the transition metall dichalcogenides

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Abstract

1. Проведены предсказания и обнаружено несколько новых структур, существенно отличающихся от ранее известных H и T
2. Предсказанные структуры характеризуются динамической стабильностью, однако энтальпии их образования выше энтальпий H и T структур.
3. С помощью автоматизированных топологических алгоритмов проведён поиск топологических аналогов. Все структуры, включая fxt и fes характеризуются уникальными топологическими типами и не имеют структурных аналогов в ICSD. Исключение составляет horH структура, характеризующаяся той же топологией, что и T-структура.

Introduction

Transition metall dichalcogenides (TMD) crystallise in four main structural types: CdI₂, MoS₂, FeS₂ (pyrite-type and less frequently marcasite-type). First two structural types are characterised by the layered structures with Ch-TM-Ch (Ch—chalcogenide, TM—transition metall) sandwiches bonded to each other by the weak Van-der-Waals bonds. These quasi-2D sandwiches attract considerable attention due to their semiconducting, superconduting and magnetic properties. In particular, 2D layers of MoS₂, WS₂, MoSe₂, WSe₂, and MoTe₂ have a direct band gap and can be used as transistors and due to the strong spin-orbit

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coupling are perspective spintronics. Due to trigonal and hexagonal symmetry of the separate sandwich-layers produced from MoS₂ and CdI₂ structures, they can be designated as 1H and 1T respectively, according to Ramsdell notation.

The top-layer of sulphur in the the sandwich of MoS₂ was successfully changed on the layer of Se with the formation of the so-called Janus SMoSe structure [?]. In the present work we investigate stability and energy of Janus structures sufficiently different in geometry and topology from T and H structures. Using topological anlysis, we analyse uniqueness of the found structures and access possibility of their experimental synthesis. Preliminary calculations of the electronic structures shows that some of the found structures are direct band gap semiconductors (Захар, поправь меня, если я не прав). The special paper will be devoted to the results of these calculations.

Crystal structures of MCh₂, M=Mo,W,Vm, Ch=S,Se

At ambient conditions MoS₂, WS₂, MoSe₂, WSe₂ crystallise in the arche-type molibdenite (MoS₂) structure. In these structure atoms of chalcogenes form close-packed layers placed exactly one under another along c-axis. TM atoms occupy center of trigonal prismatic cavities between the layers. Different stacking of such a 2D layers produce different polytypes. If the repition stacking is reprroduced through each two layers the structure has hexagonal symmetry and according to Ramsdell notation is denoted as 2H-polytype. As in the present manuscript, we consider only isolated 2D-layers, we will designate them as H-layers.

If the layers of chalcogene atoms are shifted such that the top-layer is placed in triangular holes, the coordination polyhedron changes from trigonal prism to octahedron and archetype CdI₂ structure is formed. Due to trignaly symmetry of sandwich-layers of such a structure, they can be designated as T-layers.

The 1T structure for TMCh₂ compounds, where TM=Mo, W, and V, and S, Se, and Te are less energetically favourable than 2H structres of the same compoistion. However, these 1T structures can be stabilised by the impurities of Li atoms or by some deformations (Захар, добавь тут ссылку).

V is different from W and Mo in that it does not produce dichalcogenides at ambient conditions. VSe₂ is known in the form 2H structure with additional V adoms in the centers of empty trigonal prisms in between the sandwiches and composition Se₂V_{1.005}

1 Methods

2 Results

2.1 Similarity and differences of H, T, fxt and fes structures

Although H and T structures are characterised by the different coordination polyhedrons, they are similar in the manner of their interconnection. H structure consists of trigonal prisms MoS_6 (MoS_3Se_3 for Janus structures), and T structure – of the octahedra of the same composition (Figure 1). Each trigonal prism share all three vertical edges with the neighboring prisms and does not share any faces. As the result each vertice and each vertical edge of the trigonal prism is common for three prisms (Figure 1). Similarly in T structure, each octahedron share all edges inclined to the plane of sulphur atoms with neighbouring octahedra, and each vertice is common for three octahedra (Figure 1). Bond valence of Mo–S bond is nearly equal to $+4/6$ and there are necessary three such a bonds to compensate negative charge of 2^- of the sulphur atom. The interconnection through the edges but provides the longer distance between high-charged Mo^{4+} ions in comparison with interconnection through the faces, thus reducing the energy of Coulomb interaction.

The recently found fes and fxt structures are also characterised by the trigonal prismatic coordination. However, in these structure prisms are connected not only through edges but also through the faces. The whole structure can be constructed from the two edge-connected trigonal prisms (Figure ??b). As the result, the enthalpy of fxt and fes structures are higher than that of H structure, in full accordance with the Pauling rule [?]. In fxt and fes structures, as well as in H and T structures, each at sulphur are connected to three Mo atoms in fxt and fes structure, providing the local charge balance.

H and T structures provide the most homogenic distribution of sulphur and Mo atoms. Both Mo and S nets consists of the geometrically equal triangular loops. Edge-sharing interconnection of trigonal prisms realised in fxt and fes structures inevitably results in the appearance of the cavities bigger than that in H and T structures. In fes structure the cavities have the form of the slightly compressed cube (Figure ??). The volume of these cavities is almost two times larger than the volume of the cavities in H structure (38.8 against 17.7 \AA^3). In case of fxt structure, the volume of hexagonal cavities (Figure ??) is almost 8 times larger than in H structure (137.8 against 17.7 \AA^3). In contrast to trigonal prisms, the face-sharing of the right octahedra seems to be problematic for quasi 2D structure, as it results in the deviation from the flat arrangement (Figure ??b). However, as it will be shown below, the dynamically stable structures with face sharing deformed octahedra can be also produced.

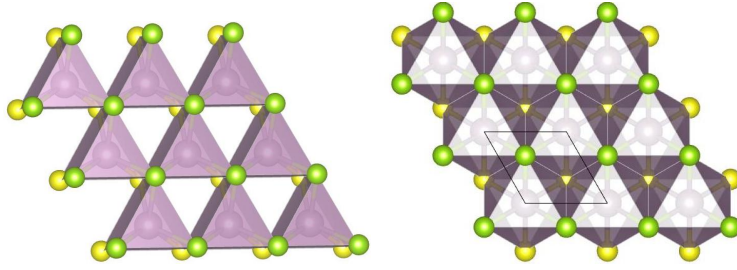


Figure 1: Packing of trigonal prisms and octahedra in H and T structures

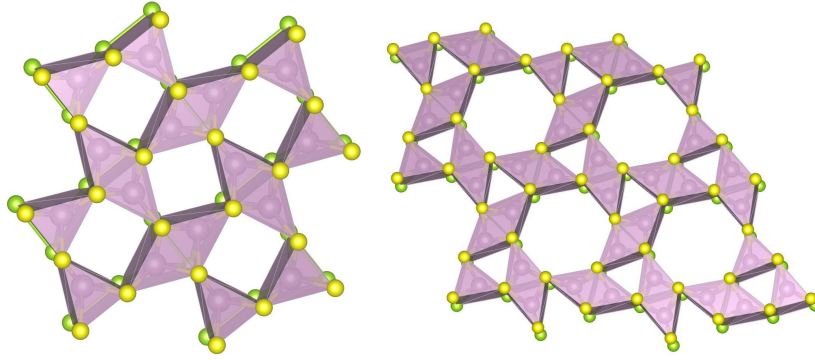


Figure 2: Packing of trigonal prisms in fes and fxt structures.

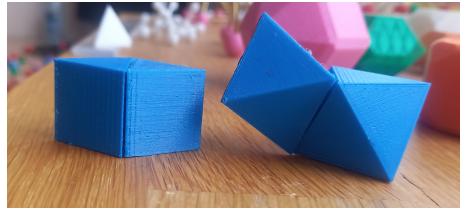


Figure 3: Two face-shared trigonal prisms and octahedra, the deviation from the horizontal plane in the last case is clearly visible

2.2 The new crystal structures

2.2.1 Structures with trigonal prismatic coordination

To compare topologies of H, fes, and fxt structures and produce similar structures with trigonal prismatic coordination, we present the structures as different fillings of the hexagonal net of sulphur atoms (Figure 4). H-structure presents the most symmetric filling similar to chess-board with triangular cells. The fes

structure can be also considered as the chess-board, but with doubled triangular cell, having the form of rhombuses. After optimisation these rhombuses transform in the described above right squares. In fxt structure the white loops are of two types. The first are three doubled triangular (rhombuses) connected through the faces, having the form of right hexagons. The second are primitive triangles. The optimisation does not sufficiently change the form of the white loops, only slightly deforming hexagons.

Three new structures were produced by means of the filling of triangles in the hexagonal net of the sulphur atoms, named test1, test2, and test3. We failed to produce new structures obeying the local charge balance, i.e. the structures in which each vertex of the trigonal prism is common for two other prisms. In the structure test1, each sulphur atom is common for two or four filled prisms, in test2 and test 3 – for 2, 3, and 4 (Figure 4). Test 3 structure is different from other structures in that it is characterised by the presence of trigonal prisms with two common faces, while in all other structures prisms have no more than one common face. This results in the shortening of the Mo–Mo–Mo distance, for Mo atoms placed in the neighbouring trigonal prisms. Optimisation of test 3 structure sufficiently affects the arrangement of sulphur atoms coordinating these closely spaced Mo atoms, as well as atoms themselves. In the final structure the net of sulphur atoms is not the hexagonal one and coordinations of some of Mo atoms, change from trigonal prismatic to subsquare quadratic.

Presence of common edges and faces of [MoO₆] trigonal prisms in fxt, fes, test1, test2, and test3 structure results in shorter Mo–Mo distances in comparison with 1H structure, where prisms have only common edges. In H structure Mo atoms form regular hexagonal net with all Mo–Mo bonds being equal to 3.25 Å. In fxt, fes, test1, test2, and test3 structures Mo–Mo distances vary in some range, with formation of Mo–Mo dimer connected by the stronger bonds. In optimised H structure, the Mo–Mo bond distances are equal to 3.25 Å, in H-hor it reaches 3.08 Å, in test 1 – 2.9 Å, in fxt, fes, and test2 – in average 2.62 Å, and test3 is characterised by the shortest Mo–Mo distance 2.22 Å. The dimers are in turn connected in chains and layers by the weaker bonds. Presence of Mo–Mo dimers can result in new electronic properties of the new structures are not observed in H structure. As we have mentioned this question will be considered in the special paper.

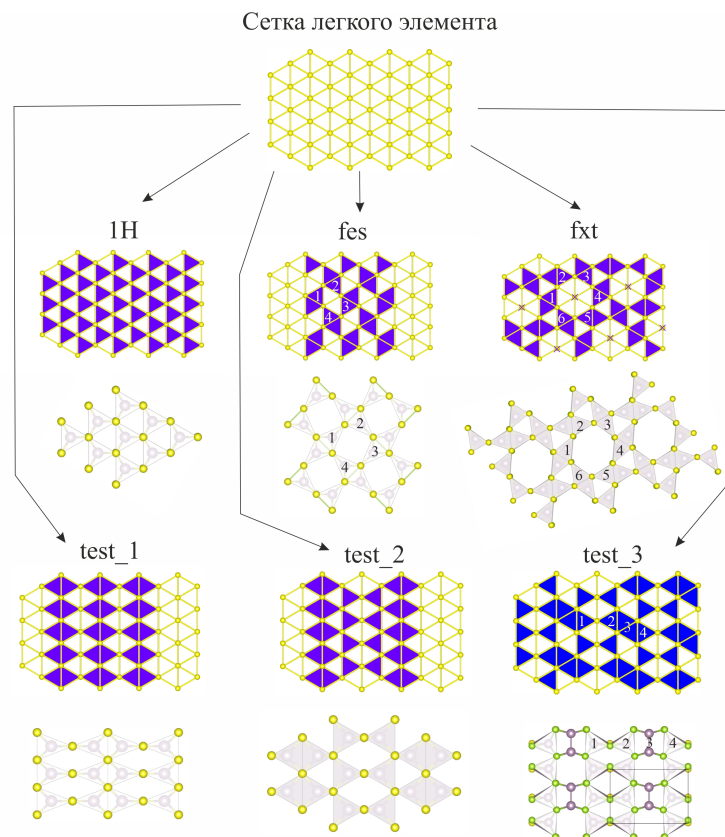


Figure 4: The initial and optimised structures of MoSSe. Тут нужно убрать связь Mo-Mo для test3 и вомзможно показать Mo3 в профиль

Another structure characterising by trigonal prismatic coordination was found by means of USPEX code. It is sufficiently different from all the considered above structures in that three-fold axes of trigonal prisms are parallel to the plane of sulphur atoms. As the result the loops of the net sulphur atoms is not more hexagonal, but square. This structure was called Hhor (from H-horizonta1)

2.2.2 Structures with octahedral coordination

As it was mentioned above T structure, composed of closely packed octahedra does not give such a flexibility as H-structure, as contact of octahedra through the face results in the coorigation of the plane of sulphur atoms. One such a structure with face-shared octahedra have been found with AIRSS code. In this structure each octahedra have four common edges and one common face. The presence of the common face results in the sufficient corrugation of the layers of sulphur, in contrast to earlier considered structures, which a relatively flat

ones. This structure was called T-hor.

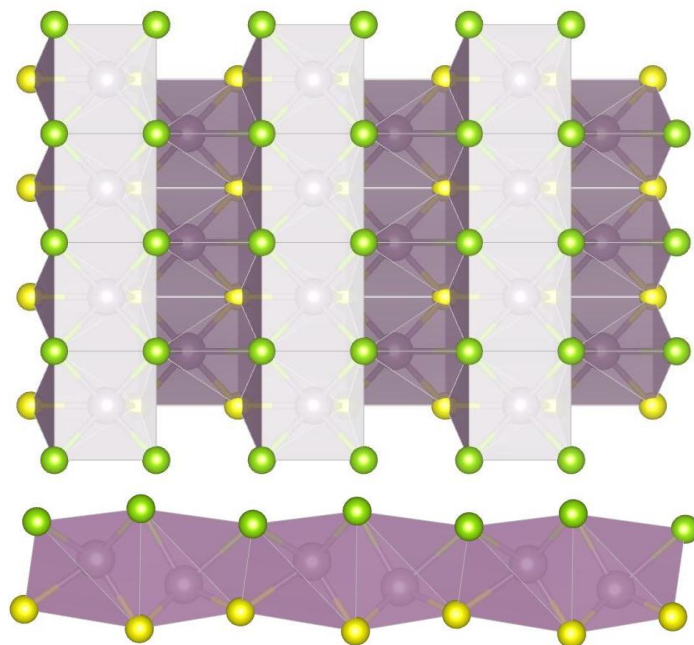


Figure 5: H-hor crystal structure perpendicular and along the layer.

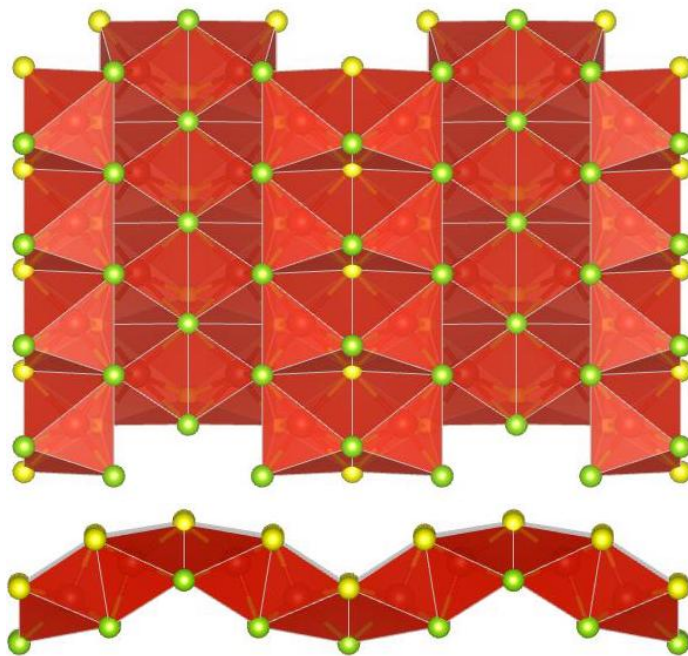


Figure 6: T-hor crystal structure perpendicular and along the layer.

2.2.3 5-coordinated crystal structure

Crystal structure with 5-coordinated Mo atoms were revealed with AIRSS code and have been called airss-1. This structure have not analogues with any structures described above. Mo atoms are surrounded by 5 chalcogenes arranged in tetragonal or ditrigonal pyramids. Two tetragonal pyramids and one ditrigonal pyramid connected through the edges are grouped in clusters. The adjacent clusters are connected through the common edges. Between clusters there are the holes, the size of which is comparable with the size of the clusters itself.

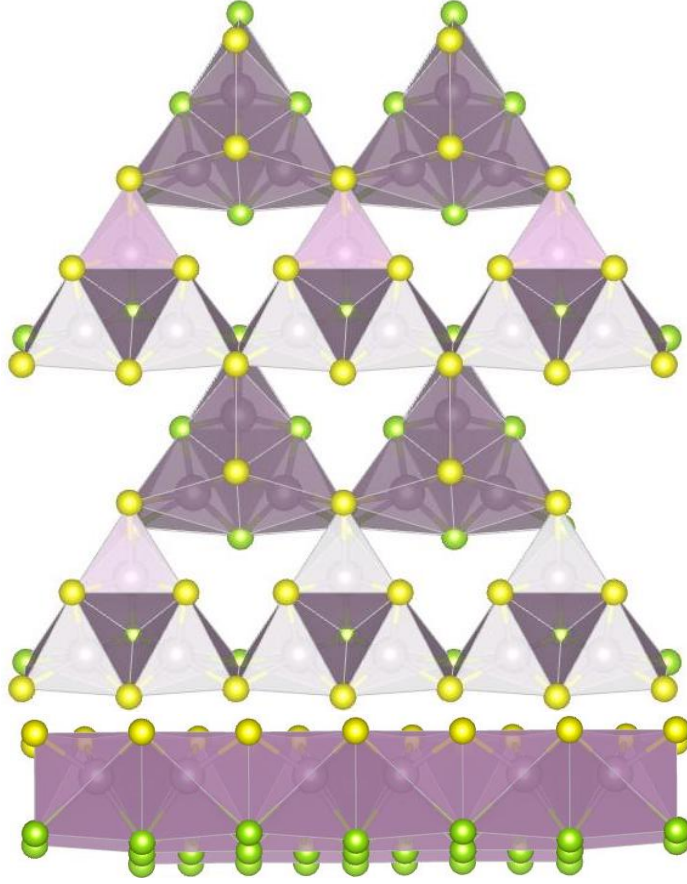


Figure 7: AIRSS-1 structure with 5-coordinated Mo atoms perpendicular and along the layer.

2.2.4 Crystal structure consisting of mixed layers of TM and Ch (chalcogene)

The structure in which TM are sufficiently shifted from the center towards upper and bottom layer was revealed for SVSe composition with AIRSS code and have been called airss-3. V atoms in this structure are characterised by the coordination numbers of five and six, and coordination polyhedron in the forms of tetragonal pyramid and trigonal prism respectively. Structure can be presented as the combination of double chains one is with the subhorizontal faces of [SV4] composition in the upper layer and another is with subhorizontal faces of [SeV4] composition in the bottom layer. Polyhedrons are connected through common edges. Each tetragonal pyramid shares six out of eight common faces and trigonal pyramid – three out of nine.

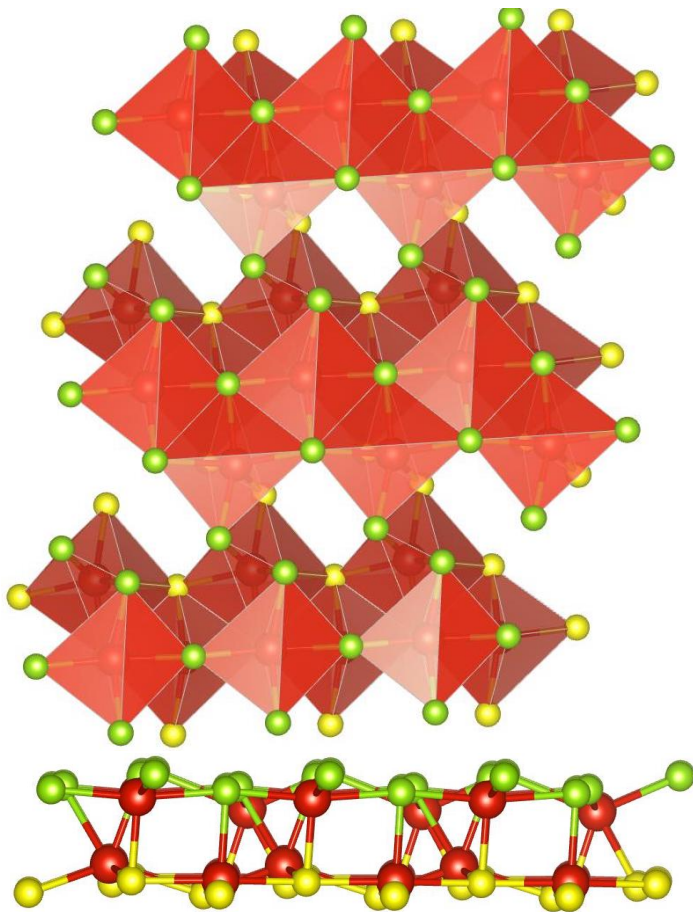


Figure 8: AIRSS-3 structure with V atoms shifted towards the planes of chalcogenes.

2.2.5 The uniqueness of the new structures

The search of the structural analogues of the new structures of the dichalcogenides have not only fundamental importance but also of a practical application. Similar structures can be used as the seeds (подложки) for the synthesis of the new structures, which are energetically less favourable than H and T structures.

To answer the question, whether the found structures are unique or there are similar representatives in ICSD we have performed topological search. The obtained results have shown that all the found structures, except of H-hor, are unique and similar structures are not found in ICSD. The same is true about the earlier known fxt and fes structures, similar structures of which have not also been found. The H-hor structure belong to the same kgd topological type as

the T structure. This mean that one structure can be transformed into another without breaking of the bonds. However the geometrical difference of H-hor and T structures is sufficient and transformation of one structure into the other require changing of coordination polyhedron from trigonal prism to octahedron.

2.3 Stability of the predicted structures